

## **TDA7491HV**

## 20 W + 20 W dual BTL class-D audio amplifier

#### **Features**

- 20 W + 20 W continuous output power:  $R_L = 8 \Omega$ , THD = 10% at  $V_{CC} = 18 V$
- Wide range single supply operation (5 V 19 V)
- High efficiency ( $\eta = 90\%$ )
- Four selectable, fixed gain settings of 20 dB, 26 dB, 30 dB and 32 dB
- Differential inputs minimize common-mode noise
- Filterless operation
- No 'pop' at turn-on/off
- Standby and mute features
- Short circuit protection
- Thermal overload protection
- Externally synchronizable



### **Description**

The TDA7491HV is a dual BTL class-D audio amplifier with single power supply designed for LCD TVs and monitors.

Thanks to the high efficiency and slug-down package no heatsink is required.

Furthermore, the filterless operation allows a reduction in the external component count.

The TDA7491HV is pin to pin compatible with the TDA7491P and TDA7491LP.

Table 1. Device summary

Order code	Operating Temp. range	Package	Packing
TDA7491HV	0° to 70° C	PowerSSO-36 (slug down)	Tube
TDA7491HV13TR	0° to 70° C	PowerSSO-36 (slug down)	Tape and reel

Contents TDA7491HV

## **Contents**

1	Devi	ice block diagram
2	Pin (	description 5
	2.1	Pin-out
	2.2	Pin list
3	Elec	trical specifications7
	3.1	Absolute maximum ratings
	3.2	Thermal data 7
	3.3	Electrical specifications 7
4	Cha	racterization curves 9
	4.1	For 8 $\Omega$ loads
	4.2	For 6 $\Omega$ loads
	4.3	For 4 $\Omega$ loads
5	Pack	kage information
6	Арр	lication circuit
7	Арр	lication information
	7.1	Mode selection
	7.2	Gain setting
	7.3	Input resistance and capacitance
	7.4	Internal and external clocks
		7.4.1 Master mode (internal clock)
		7.4.2 Slave mode (external clock)
	7.5	Filterless modulation
	7.6	Output low-pass filter
	7.7	Protection function
	7.8	Diagnostic output
	7.9	Heatsink requirements

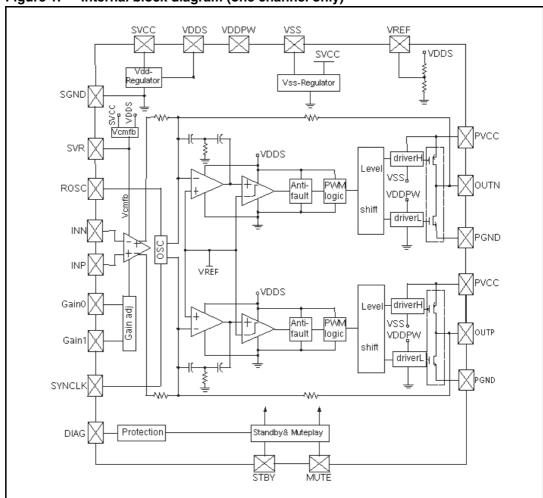
TDA7491H	IV	Contents
Ω	Revision history	25

**/**//

# 1 Device block diagram

Figure 1 shows the block diagram of one of the two identical channels of the TDA7491HV.

Figure 1. Internal block diagram (one channel only)

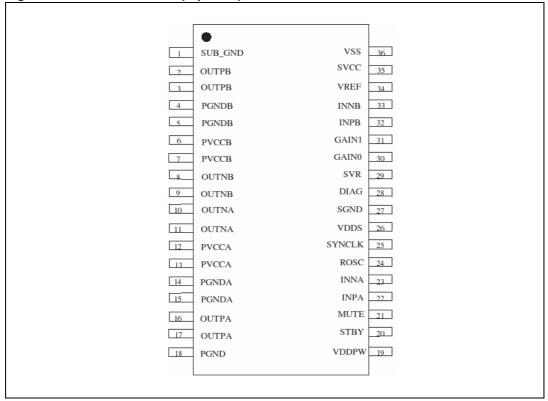


TDA7491HV Pin description

# 2 Pin description

### 2.1 Pin-out

Figure 2. Pin connection (top view)



5/26

Pin description TDA7491HV

## 2.2 Pin list

Table 2. Pin description list

Number	Name	Туре	Description
1	SUB_GND	POWER	Connect to the frame
2,3	OUTPUTB	OUT	Positive PWM for right channel
4,5	PGNDB	POWER	Power stage round for right channel
6,7	PVCCB	POWER	Power supply for right channel
8,9	OUTNB	OUT	Negative PWM output for right channel
10,11	OUTNA	OUT	Negative PWM output for right channel
12,13	PVCCA	POWER	Power supply for left channel
14,15	PGNDA	POWER	Power stage round for left channel
16,17	OUTPA	OUT	Positive PWM output for left channel
18	PGND	POWER	Power stage round
19	VDDPW	OUT	3.3 V (nominal) regulator output referred to ground for power stage
20	STBY	INPUT	Standby mode control
21	MUTE	INPUT	Mute mode control
22	INPA	INPUT	Positive differential input of left channel
23	INNA	INPUT	Negative differential input of left channel
24	ROSC	OUT	Master oscillator frequency-setting pin
25	SYNCLCK	IN/OUT	Clock in/out for external oscillator
26	VDDS	OUT	3.3 V (nominal) regulator output referred to ground for signal blocks
27	SGND	POWER	Signal round
28	DIAG	OUT	Open-drain diagnostic output
29	SVR	OUT	Supply voltage rejection
30	GAIN0	INPUT	Gain setting input 1
31	GAIN1	INPUT	Gain setting input 2
32	INPB	INPUT	Positive differential input of right channel
33	INNB	INPUT	Negative differential input of right channel
34	VREF	OUT	Half VDDS (nominal) referred to ground
35	SVCC	POWER	Signal power supply
36	VSS	OUT	3.3 V (nominal) regulator output referred to power supply
	•	•	

## 3 Electrical specifications

### 3.1 Absolute maximum ratings

Table 3. Absolute maximum ratings

Symbol	Parameter	Value	Unit
VCC	DC supply voltage for pins PVCCA, PVCCB, SVCC	23	V
T <sub>op</sub>	Operating temperature	0 to 70	°C
Tj	Junction temperature	-40 to 150	°C
T <sub>stg</sub>	Storage temperature	-40 to 150	°C

#### 3.2 Thermal data

Table 4. Thermal data

Symbol	Parameter	Min	Тур	Max	Unit
R <sub>th j-case</sub>	Thermal resistance, junction to case		2	3	
R <sub>th j-amb</sub>	Thermal resistance, junction to ambient (mounted on recommended PCB) <sup>(1)</sup>		24		°C/W

<sup>1.</sup> FR4 with vias to copper area of 9 cm<sup>2</sup> (see also Section 7.9: Heatsink requirements on page 24).

## 3.3 Electrical specifications

Unless otherwise stated, the results in *Table 5* below are given for the conditions: VCC = 18 V, R<sub>L</sub> (load) = 8  $\Omega$ , R<sub>OSC</sub> = 39 k $\Omega$ , C1 = 100 nF, f = 1 kHz, G<sub>V</sub> = 20 dB, and Tamb = 25° C.

Table 5. Electrical specifications

Symbol	Parameter	Condition	Min	Тур	Max	Unit
VCC	Supply voltage for pins PVCCA, PVCCB, SVCC		5		18	V
Iq	Total quiescent			26	35	mA
I <sub>qSTBY</sub>	Quiescent current in standby			2.5	5.0	μΑ
V <sub>OS</sub>	Output offset voltage	Play mode	-200		200	mV
V <sub>OS</sub>	Output offset voltage	Mute mode	-300		300	mV
I <sub>OC</sub>	Over current protection threshold	$R_L = 0 \Omega$	3	5		Α
Тј	Junction temperature at thermal shut-down			150		°C
R <sub>i</sub>	Input resistance	Differential input	55	60		kΩ
V <sub>OV</sub>	Over voltage protection threshold		19	21		

5/

Table 5. Electrical specifications (continued)

Symbol	Parameter	Condition	Min	Тур	Max	Unit	
ם	Power transistor on resistance	High side		0.2		0	
R <sub>dsON</sub>	Power transistor on resistance	Low side		0.2	Ω		
Б	Outrat a surra	THD = 10%		20			
P <sub>o</sub>	Output power	THD = 1%		16		W	
_	Outrost recover	R <sub>L</sub> = 8 Ω, THD = 10% VCC = 12 V		9.5			
P <sub>o</sub>	Output power	R <sub>L</sub> = 8 Ω, THD = 1% VCC = 12 V		7.2		W	
P <sub>D</sub>	Dissipated power	P <sub>o</sub> = 20 W + 20 W, THD = 10%		4.0		w	
η	Efficiency	P <sub>o</sub> = 20 W + 20 W	80	90		%	
THD	Total harmonic distortion	P <sub>o</sub> = 1 W		0.1	0.4	%	
G <sub>V</sub>	Closed loop gain	GAIN0 = L, GAIN1 = L	18	20	22		
		GAIN0 = L, GAIN1 = H	24	26	28	dB	
		GAIN0 = H, GAIN1 = L	28	30	32		
		GAIN0 = H, GAIN1 = H	30	32	34		
ΔG <sub>V</sub>	Gain matching		-1		1	dB	
СТ	Cross talk	f = 1 kHz		50		dB	
eN	Total input noise	A Curve, G <sub>V</sub> = 20 dB		20		\/	
GIN	Total input hoise	f = 22 Hz to 22 kHz		25	35	μV	
SVRR	Supply voltage rejection ratio	Fr = 100 Hz, Vr = 0.5 V, C <sub>SVR</sub> = 10 μF	40	50		dB	
T <sub>r</sub> , T <sub>f</sub>	Rise and fall times			50		ns	
F <sub>SW</sub>	Switching frequency	Internal oscillator	290	310	330	kHz	
Е	Output switching frequency	With internal oscillator (1)	250			1	
F <sub>SWR</sub>	Output switching frequency	With external oscillator (2)	250			kHz	
V <sub>inH</sub>	Digital input high (H)		2.3			v	
V <sub>inL</sub>	Digital input low (L)				0.8	] <b>'</b>	
		STBY < 0.5 V, MUTE = X	Standby				
Function mode	Standby, mute and play modes	STBY > 2.5 V, MUTE < 1 V	Mute				
		STBY > 2.5 V, MUTE > 2 V	Play				
A <sub>MUTE</sub>	Mute attenuation	VMute = 1 V	60	80		dB	

<sup>1.</sup>  $F_{SW} = 10^6 / (64 * R_{OSC} + 440)$  kHz,  $f_{SYNCLK} = 2 * F_{SW}$  with R1 in k $\Omega$  (see *Figure 22*).

<sup>2.</sup>  $F_{SW} = f_{SYNCLK} / 2$  with the frequency of the external oscillator.

TDA7491HV Characterization curves

## 4 Characterization curves

### 4.1 For 8 $\Omega$ loads

Figure 3. Output power vs supply voltage

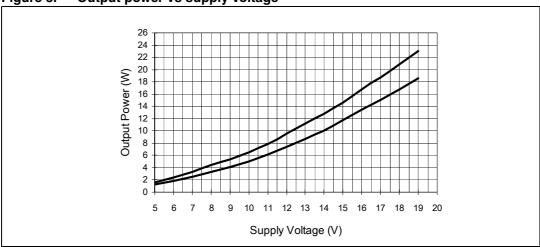
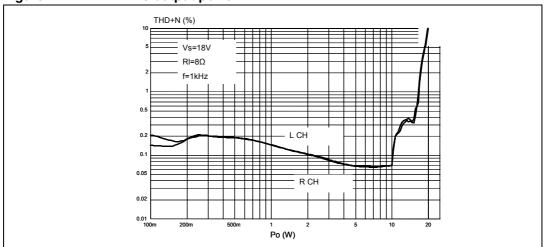


Figure 4. THD + N vs output power



Characterization curves TDA7491HV

Figure 5. THD + N vs output power (without LC filter)

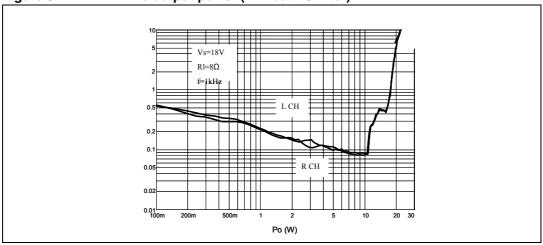


Figure 6. THD + N vs frequency

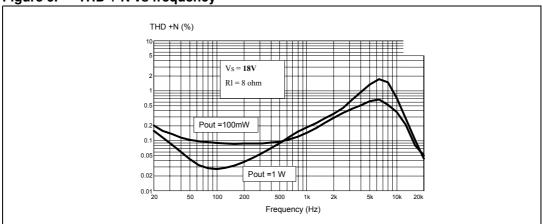
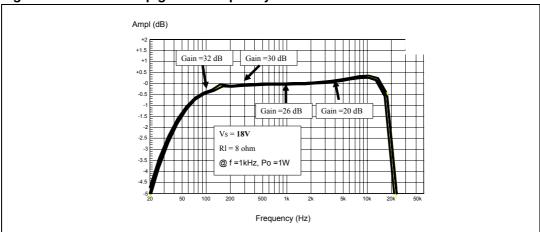


Figure 7. Closed-loop gain vs frequency



TDA7491HV Characterization curves

Figure 8. Cross talk vs frequency

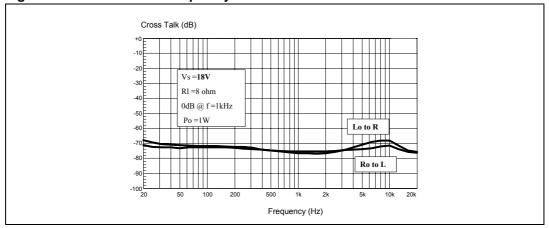


Figure 9. Power dissipation and efficiency vs output power (per channel)

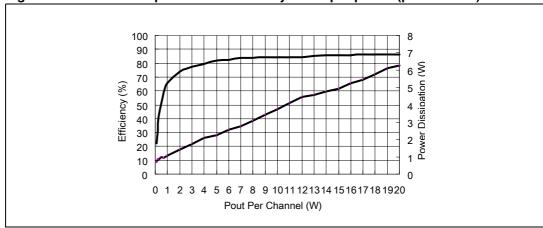
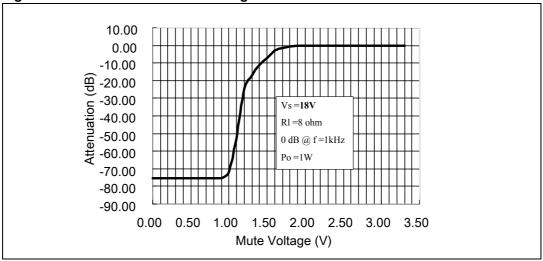


Figure 10. Attenuation vs mute voltage

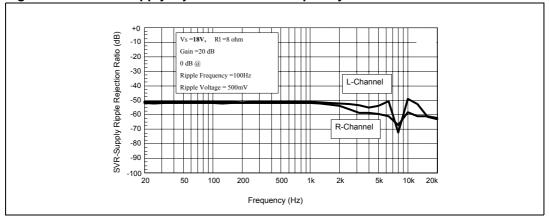


**TDA7491HV Characterization curves** 

50 45 40 (¥±) 30 ± 25 No Load 20 Play Mode 15 10 6 7 8 9 10 11 12 13 14 15 16 17 18 19 20 5 Supply Voltage (V)

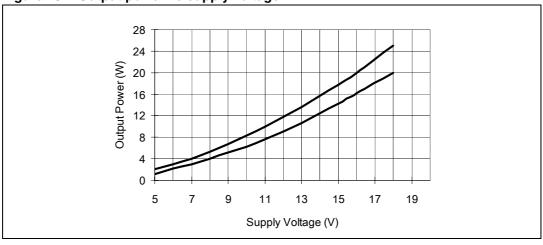
Figure 11. Total quiescent current vs supply voltage

Figure 12. Power supply rejection ratio vs frequency



#### For 6 $\Omega$ loads 4.2





TDA7491HV Characterization curves

Figure 14. THD vs output power

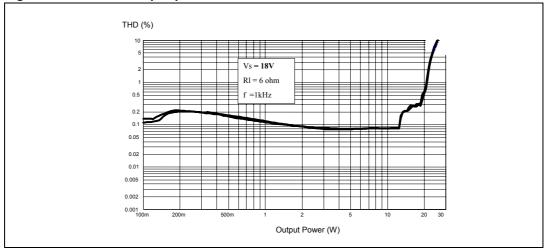


Figure 15. Frequency response

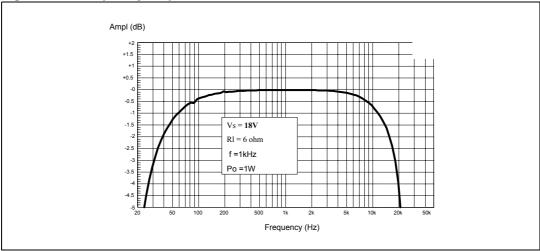
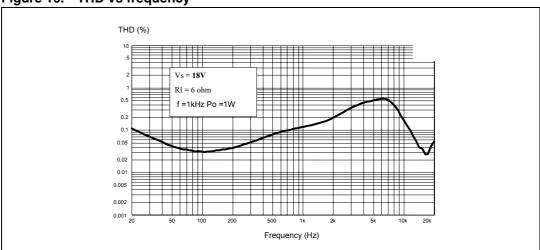


Figure 16. THD vs frequency



**577** 

**TDA7491HV Characterization curves** 

Figure 17. Cross talk vs frequency

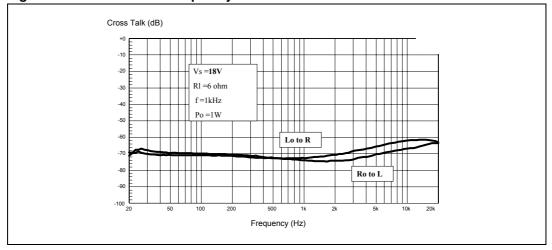


Figure 18. FFT performance (0 dB)

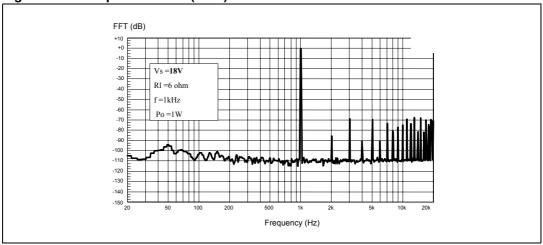
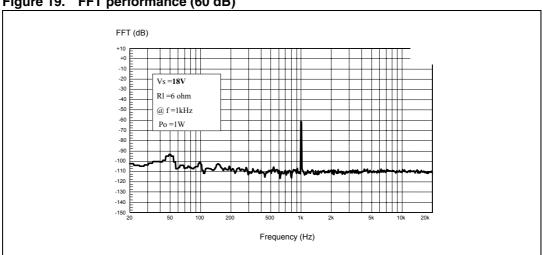


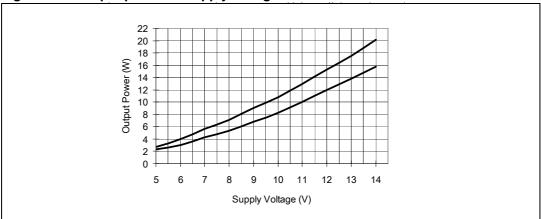
Figure 19. FFT performance (60 dB)



TDA7491HV Characterization curves

## 4.3 For 4 $\Omega$ loads

Figure 20. Output power vs supply voltage



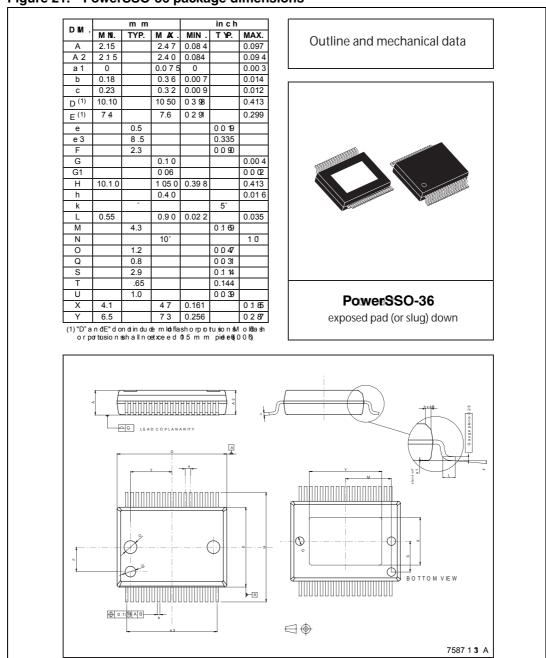
Package information TDA7491HV

## 5 Package information

In order to meet environmental requirements, ST offers these devices in ECOPACK<sup>®</sup> packages. These packages have a Lead-free second level interconnect. The category of second Level Interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark.

ECOPACK specifications are available at: http://www.st.com.

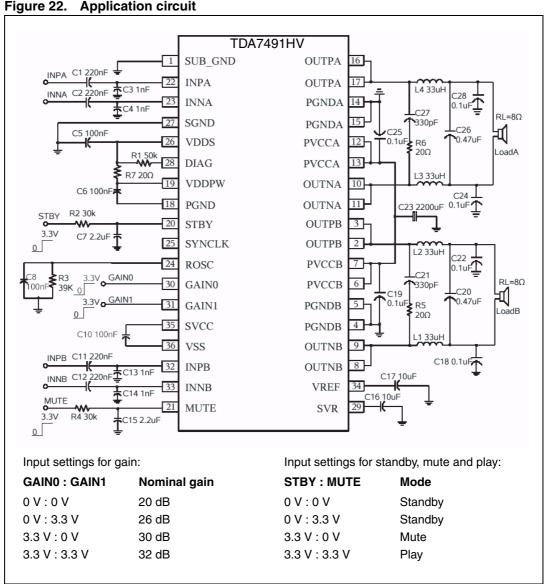
Figure 21. PowerSSO-36 package dimensions



**TDA7491HV Application circuit** 

#### **Application circuit** 6

Figure 22. Application circuit



## 7 Application information

#### 7.1 Mode selection

The three operating modes of the TDA7491HV are set by the two inputs STBY (pin 20) and MUTE (pin 21).

- Standby mode: all circuits are turned off, very low current consumption.
- Mute mode: inputs are connected to ground and the positive and negative PWM outputs are at 50% duty cycle.
- Play mode: the amplifiers are active.

The protection functions of the TDA7491HV are realized by pulling down the voltages of the STBY and MUTE inputs shown in *Figure 23*. The input current of the corresponding pins must be limited to 200  $\mu$ A.

Table 6. Mode settings

Mode Selection	STBY	MUTE
Standby	L (1)	X (don't care)
Mute	H <sup>(1)</sup>	L
Play	Н	Н

<sup>1.</sup> Drive levels defined in Table 5: Electrical specifications on page 7.

Figure 23. STBY and MUTE circuit

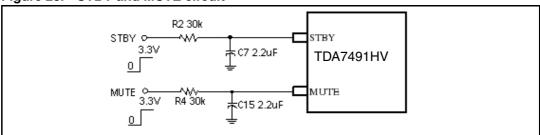
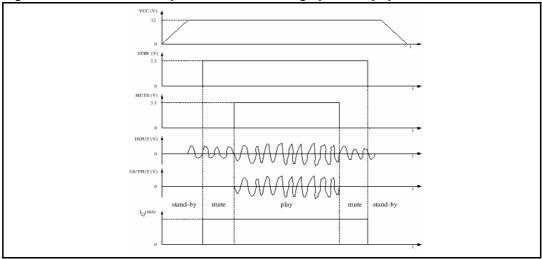


Figure 24. Turn on/off sequence for minimizing speaker "pop"



### 7.2 Gain setting

The gain of the TDA7491HV is set by the two inputs, GAIN0 (pin 30) and GAIN1 (pin 31). Internally, the gain is set by changing the feedback resistors of the amplifier.

Table 7. Gain settings

GAIN0	GAIN1	Nominal gain, G <sub>v</sub> (dB)
0	0	20
0	1	26
1	0	30
1	1	32

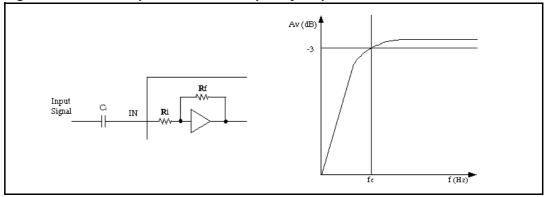
### 7.3 Input resistance and capacitance

The input impedance is set by an internal resistor  $Ri = 60 \text{ k}\Omega$  (typical). An input capacitor (Ci) is required to couple the AC input signal.

The equivalent circuit and frequency response of the input components are shown in *Figure 25*. For Ci = 220 nF the high-pass filter cut-off frequency is below 20 Hz:

$$fc = 1 / (2 * \pi * Ri * Ci)$$

Figure 25. Device input circuit and frequency response



#### 7.4 Internal and external clocks

The clock of the class-D amplifier can be generated internally or can be driven by an external source.

If two or more class-D amplifiers are used in the same system, it is recommended that all devices operate at the same clock frequency. This can be implemented by using one TDA7491HV as master clock, while the other devices are in slave mode (that is, externally clocked. The clock interconnect is via pin SYNCLK of each device. As explained below, SYNCLK is an output in master mode and an input in slave mode.

#### 7.4.1 Master mode (internal clock)

Using the internal oscillator, the output switching frequency,  $F_{SW}$ , is controlled by the resistor,  $R_{OSC}$ , connected to pin ROSC:

$$F_{SW} = 10^6 / (64 * R_{OSC} + 440) \text{ kHz}$$

where  $R_{OSC}$  is in  $k\Omega$ .

In master mode, pin SYNCLK is used as a clock output pin, whose frequency is:

For master mode to operate correctly then resistor  $R_{OSC}$  must be less than 60  $k\Omega$  as given below in *Table 8*.

#### 7.4.2 Slave mode (external clock)

In order to accept an external clock input the pin ROSC must be left open, that is, floating. This forces pin SYNCLK to be internally configured as an input as given in *Table 8*.

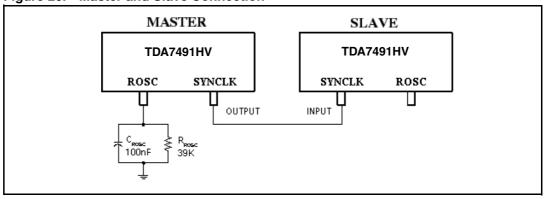
The output switching frequency of the slave devices is:

$$F_{SW} = F_{SYNCLK} / 2$$

Table 8. How to set up SYNCLK

	Mode	ROSC	SYNCLK		
Master		$R_{OSC} < 60 \text{ k}\Omega$	OUTPUT		
Slave		Floating (not connected)	INPUT		

Figure 26. Master and Slave Connection



### 7.5 Filterless modulation

The output modulation scheme of the BTL is called unipolar pulse width modulation (PWM). The differential output voltages change between zero and +Vcc and between zero and -Vcc. This is in contrast to the traditional bipolar PWM outputs which change between +Vcc and -Vcc.

An advantage of this scheme is that it effectively doubles the switching frequency of the differential output waveform. The OUTP and OUTN are in the same phase when the input is zero, then the switching current is low and the loss in the load is small. In practice, a short delay is introduced between these two outputs in order to avoid the BTL output switching at the same time.

TDA7491HV can be used without a filter before the speaker, because the frequency of the TDA7491HV output is beyond the audio frequency, the audio signal can be recovered by the inherent inductance of the speaker and natural filter of the human ear.

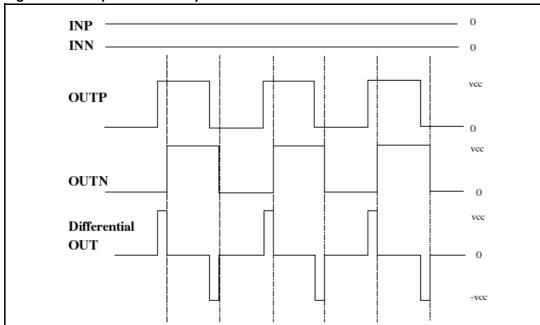


Figure 27. Unipolar PWM output

### 7.6 Output low-pass filter

To avoid EMI problems, it may be necessary to use a low-pass filter before the speaker. The cutoff frequency should be larger than 22 kHz and much lower than the output switching frequency. It is necessary to choose the L-C component values depending on the loud speaker impedance. Some typical values, which give a cut-off frequency of 27 kHz, are shown in *Figure 28* and *Figure 29* below.

Figure 28. Typical LC filter for a 8- $\Omega$  speaker

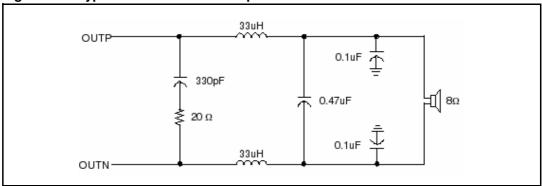
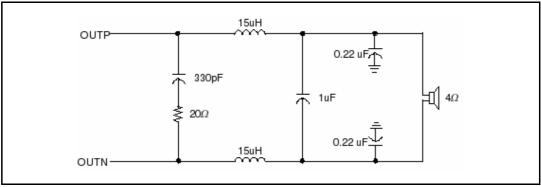


Figure 29. Typical LC filter for a 4- $\Omega$  speaker



#### 7.7 Protection function

The TDA7491HV is fully protected against over-voltages, under-voltages, over- currents and thermal overloads as explained here. See also *Table 5: Electrical specifications on page 7*.

#### Over-voltage protection (OVP)

If the supply voltage exceeds 20 V (nominal) the over-voltage protection is activated which forces the outputs to the high-impedance state. When the supply voltage drops to below the threshold value the device restarts.

#### **Under-voltage protection (UVP)**

If the supply voltage drops below 4 V (nominal) the under-voltage protection is activated which forces the outputs to the high-impedance state. When the supply voltage recovers the device restarts.

#### **Over-current protection (OCP)**

If the output current exceeds 4 A (nominal) the over-current protection is activated which forces the outputs to the high-impedance state. Periodically, the device attempts to restart. If the over-current condition is still present then the OCP remains active. The restart time,  $T_{\rm OC}$ , is determined by the R-C components connected to pin STBY.

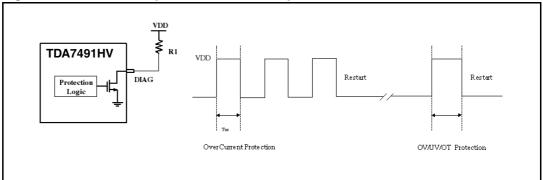
#### Thermal protection (OTP)

If the junction temperature,  $T_j$ , reaches 145° C (nominally), the device goes to mute mode and the positive and negative PWM outputs are forced to 50% duty cycle. At  $T_j = 155^{\circ}$  C (nominally), the device shuts down and the output is forced to the high impedance state. When the device cools sufficiently the device restarts.

### 7.8 Diagnostic output

The output pin DIAG is an open drain transistor. When the protection is activated it is in the high-impedance state. The pin can be connected to a power supply (< 20 V) by a pull-up resistor whose value is limited by the maximum sinking current ( $200 \mu A$ ) of the pin.

Figure 30. Behavior of pin DIAG for various protection conditions



577

### 7.9 Heatsink requirements

A thermal resistance of 24° C/W can be obtained using the PCB copper ground layer with 16 vias connecting it to the contact area for the slug. Ensure that the copper ground area is a nominal 9 cm<sup>2</sup> for 24° C/W.

Figure 31 shows the derating curves for copper areas of 4 cm<sup>2</sup> and 9 cm<sup>2</sup>.

As with most amplifiers, the power dissipated within the device depends primarily on the supply voltage, the load impedance and the output modulation level.

The maximum estimated power dissipation for the TDA7491HV is less than 4 W. When properly mounted on the above PCB the junction temperature could increase by 96° C. However, with a musical program the dissipated power is about 40% less, leading to a temperature increase of around 60° C. Even at the maximum recommended ambient temperature for consumer applications of 50° C there is still a clear safety margin before the maximum junction temperature (150° C) is reached.

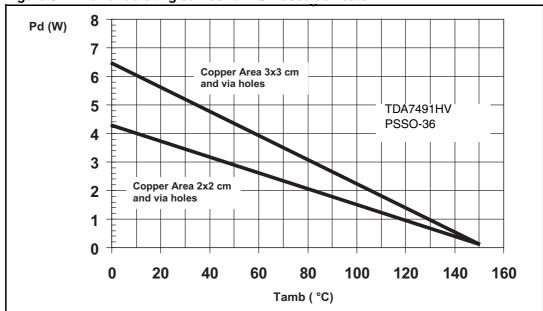


Figure 31. Power derating curves for PCB used as heatsink

577

TDA7491HV Revision history

# 8 Revision history

Table 9. Document revision history

Date	Revision	Changes
11-Dec-2007	1	Initial release.

25/26

#### Please Read Carefully:

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

UNLESS EXPRESSLY APPROVED IN WRITING BY AN AUTHORIZED ST REPRESENTATIVE, ST PRODUCTS ARE NOT RECOMMENDED, AUTHORIZED OR WARRANTED FOR USE IN MILITARY, AIR CRAFT, SPACE, LIFE SAVING, OR LIFE SUSTAINING APPLICATIONS, NOR IN PRODUCTS OR SYSTEMS WHERE FAILURE OR MALFUNCTION MAY RESULT IN PERSONAL INJURY, DEATH, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE. ST PRODUCTS WHICH ARE NOT SPECIFIED AS "AUTOMOTIVE GRADE" MAY ONLY BE USED IN AUTOMOTIVE APPLICATIONS AT USER'S OWN RISK.

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2007 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

www.st.com

577